

dB-8062H Solid State Power Amplifier



**GaN Solid State Power Amplifier
200W CW 2.0 – 6.0 GHz**

The dB-8062H is a GaN Solid State Power Amplifier operating in the frequency range of 2 to 6 GHz providing up to 200 Watts. The power supply topology uses proprietary low-noise, high-efficiency designs to operate the RF signal path. An embedded micro-controller provides the interface, control and protection functions and status indication for the Amplifier. Standard interface protocol for remote operation is Ethernet. Other protocols such as RS-232, RS-422, RS-485, CANBUS or custom interfaces are available as options. The SSPA is encased in an environmentally sealed package for outdoor and antenna pedestal mounted applications, and uses integral forced-air cooling for thermal management.

Features

- Wideband GaN SSPA
- 2.0 to 6.0 GHz, 200 W, CW
- 220 VAC
- Integral Forced Air Cooling
- Outdoor Unit
- Instant On (No Warm-Up)

Applications

- Electronic countermeasures (ECM)
- Electronic warfare (EW) and simulations
- Multi-band communication systems

dB-8062H Solid State Power Amplifier Specifications

Reliability by Design®

Electrical

Frequency Range	2.0 to 6.0 GHz
Output Power CW	200 watts, 2 - 6 GHz
Gain at rated power	53 dB minimum
RF Input Power for Saturation	0 +/- 1 dBm
Duty Cycle	100% (CW)
Input VSWR	2.0:1
Output VSWR	2.5:1
Load VSWR	1.5:1 max., Full Spec Compliance
Load VSWR	3.0:1, max. No Damage
Prime Input Voltage	220 VAC, 1 phase, 60 Hz
Prime Power	1200W max.
Interface Control	Ethernet
Pulse Modulation	50ns rise and fall time

Mechanical

Dimensions	12.0" H x 17.0" L x 13.0" W (inches) 304.8 H x 431.0 L x 431.8 W (mm)
Weight	60 lbs. (27.22kg)
Cooling	Built in forced air cooling
Connectors:	
Prime Power	MS3112E-14-5P
Control/Status	MS3112E-14-18
RF Input	Type SMA (F)
RF Output	Type N (F)

Environment

Ambient Temperature	-40° C to +40° C
Storage Temperature	-45° C to +85° C
Operating Altitude	Up to 15,000 feet ASL
Humidity	95% non-condensing

Options

Prime Input Voltage	110 VAC 3 phase 400 Hz 270 VDC
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Specifications subject to change without notice.



About dB Control

Established in 1990, dB Control Corp., a subsidiary of the Electronic Technologies Group (ETG) of HEICO Corp., supplies mission-critical, often sole-source, products worldwide to military organizations, as well as to major defense contractors and commercial manufacturers. dB Control designs and manufactures reliable high-power TWT Amplifiers (TWTAs), microwave power modules (MPMs), transmitters and power supplies with modulators for radar, electronic countermeasures (ECM) and data link applications. The company's high-power amplifiers use solid state, as well as vacuum electron devices and cover the 1 to 50 GHz frequency range. The modularity of dB Control's designs enables rapid configuration of custom products for a variety of platforms, including ground-based and high-altitude military manned and unmanned aircraft. dB Control has an outstanding record of successfully repairing, refurbishing and replacing tightly packaged high-voltage transformers, assemblies and power supplies. The company offers specialized contract manufacturing, transformer winding and testing, full vacuum encapsulation, pressure cure, conformal coating and repair depot services from its modern 40,000 square foot facilities in Fremont, California. www.dBControl.com AS-9100D and ISO-9001:2015 Certified.



dB Control Products

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